

## Low Capacitance Bidirectional Single Line TVS Protection Diode

**UM5080T DFN2 1.0×0.6**

### General Description

The UM5080T TVS protection diode is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDA's. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs. The UM5080T TVS protection diode protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. The UM5080T is available in DFN2 1.0×0.6 (compatible with SOD923/SOD882/CSP 1.0×0.6) package with working voltages of 5 volt. It gives designer the flexibility to protect bidirectional single line in applications where arrays are not practical. Additionally, it may be "sprinkled" around the board in applications where board space is at a premium. It may be used to meet the ESD immunity requirements of IEC 61000-4-2, ±30kV air, ±30kV contact discharge.

### Applications

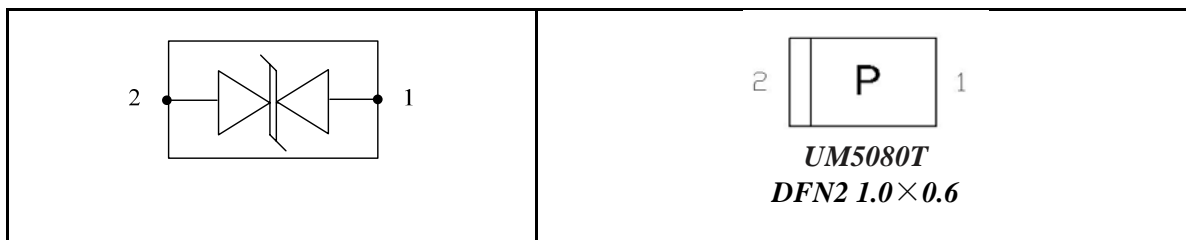
Cell Phone Handsets and Accessories  
Personal Digital Assistants (PDA's)  
Notebooks, Desktops and Servers  
Portable Instrumentation  
Cordless Phones  
Smart Card  
Digital Cameras  
MP3 Players

### Features

Transient protection for data lines to  
IEC 61000-4-2 (ESD) ±30kV (air), ±30kV  
(contact)  
Small package for use in portable electronics  
Suitable replacement for MLV's in ESD protection  
applications  
Bidirectional TVS protection  
Stand off voltages: 5V  
Low leakage current  
Low diode capacitance  
Small Body Outline Dimensions: 1.0mm×0.6mm

### Pin Configurations

### Top View



### Ordering Information

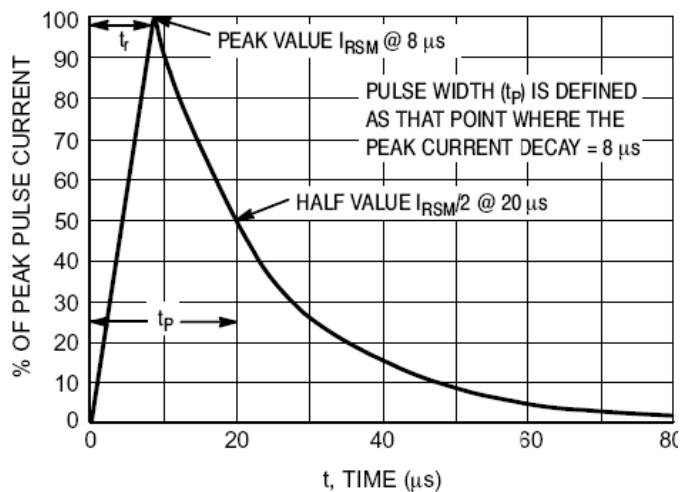
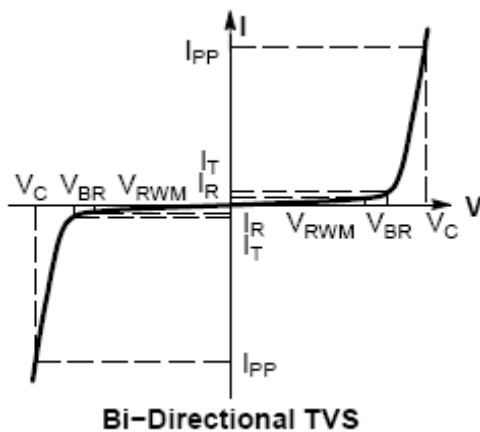
Part Number	Working Voltage	Packaging Type	Channel	Marking Code	Shipping Qty
UM5080T	5.0V	DFN2 1.0×0.6mm <sup>2</sup>	1	P	5000/7 Inch Tape & Reel

## Absolute Maximum Ratings

RATING	SYMBOL	VALUE	UNITS
Peak Pulse Power ( $t_p = 8/20\mu s$ )	$P_{PK}$	140	Watts
Maximum Peak Pulse Current ( $t=8/20\mu s$ )	$I_{PP}$	11	Amps
Lead Soldering Temperature	$T_L$	260 (10 sec.)	$^{\circ}C$
Operating Temperature	$T_J$	-55 to +125	$^{\circ}C$
Storage Temperature	$T_{STG}$	-55 to +150	$^{\circ}C$

## Symbol Definition

PARAMETER	SYMBOL
Maximum Reverse Peak Pulse Current	$I_{PP}$
Clamping Voltage @ $I_{PP}$	$V_C$
Working Peak Reverse Voltage	$V_{RWM}$
Maximum Reverse Leakage Current @ $V_{RWM}$	$I_R$
Breakdown Voltage @ $I_T$	$V_{BR}$
Test Current	$I_T$
Peak Power Dissipation	$P_{PK}$
Max. Capacitance @ $V_R = 0V, f = 1MHz$	$C_J$

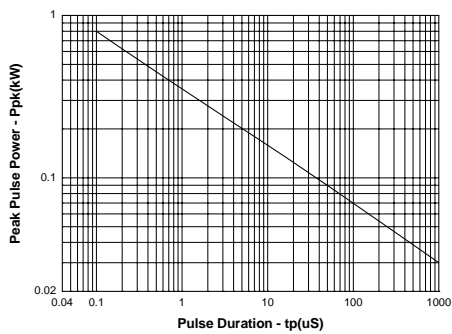


## Electrical Characteristics (T=25°C, Device for 5.0V Reverse Stand-off Voltage)

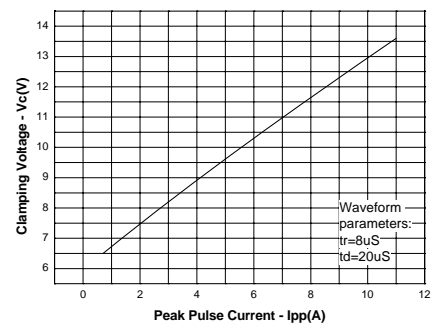
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Stand-Off Voltage	$V_{RWM}$				5	V
Reverse Breakdown Voltage	$V_{BR}$	$I_T = 1\text{mA}$	6.5		8.5	V
Reverse Leakage Current	$I_R$	$V_{RWM} = 5\text{V}, T=25^\circ\text{C}$			1	$\mu\text{A}$
Clamping Voltage	$V_C$	$I_{PP} = 5\text{A}, t_p = 8/20\mu\text{S}$			9.7	V
		$I_{PP} = 11\text{A}, t_p = 8/20\mu\text{S}$			13.6	
Junction Capacitance	$C_J$	$V_R = 0\text{V}, f = 1\text{MHz}$		45	59	pF
Junction Capacitance	$C_J$	$V_R = 2.5\text{V}, f = 1\text{MHz}$		35	45	pF

## Typical Operating Characteristics

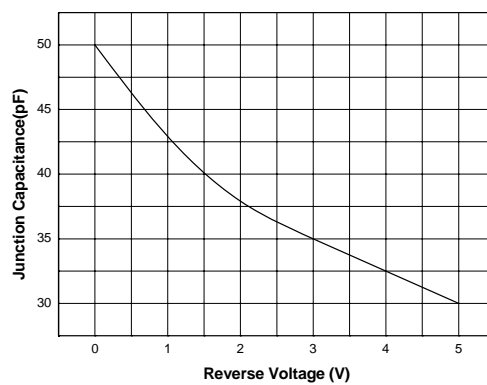
### Non-Repetitive Peak Pulse Power vs. Pulse Time



### Clamping Voltage vs. Peak Pulse Current



### Junction Capacitance vs. Reverse Voltage



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## Applications Information

### Device Connection Options

UM5080T ESD protection diode is designed to protect one bidirectional data, I/O or power supply line from the damage caused by ESD and surge pulses. The device is bidirectional and may be used on lines where the signal polarity is above ground and below ground.

### Circuit Board Layout Recommendations for Suppression of ESD

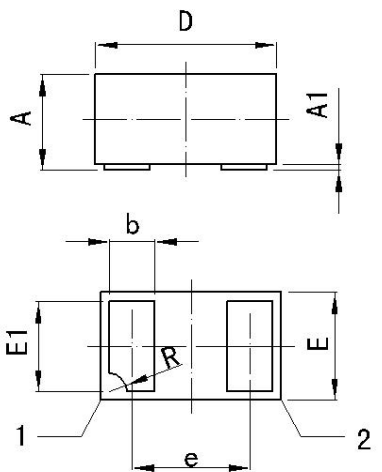
Good circuit board layout is critical for the suppression of ESD induced transients. The following guidelines are recommended:

1. Place the TVS near the input terminals or connectors to restrict transient coupling.
2. Minimize the path length between the TVS and the protected line.
3. Minimize all conductive loops including power and ground loops.
4. The ESD transient return path to ground should be kept as short as possible.
5. Never run critical signals near board edges.
6. Use ground planes whenever possible. For multilayer printed-circuit boards, use ground vias.
7. Keep parallel signal paths to a minimum.
8. Avoid running protection conductors in parallel with unprotected conductor.
9. Avoid using shared transient return paths to a common ground point.

## Package Information

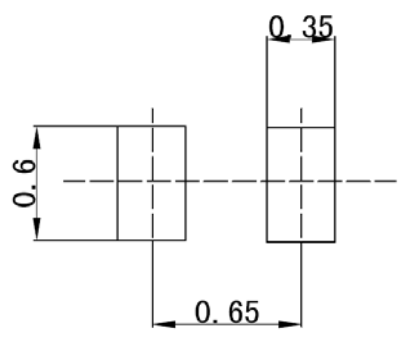
### UM5080T DFN2 1.0×0.6

#### Outline Drawing

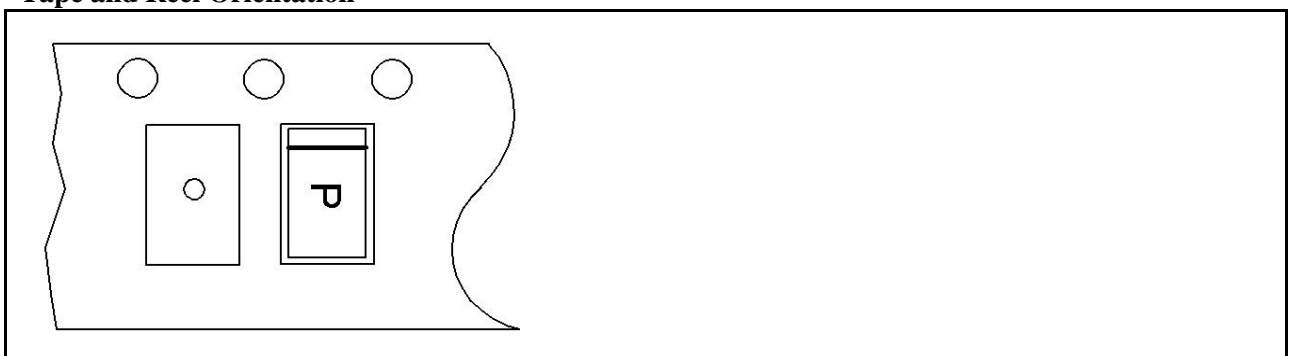
	millimeters		Inches	
	Symbol	Min	Max	Min
A	0.350	0.450	0.014	0.018
A1	0.000	0.050	0.000	0.002
b	0.190	0.300	0.007	0.012
D	0.950	1.075	0.037	0.042
E	0.550	0.675	0.022	0.027
E1	0.340	0.550	0.013	0.022
e	0.650		0.026	
R	0.050	0.150	0.002	0.006

Note: R is Optional.

#### Land Pattern

	<p>NOTES:</p> <ol style="list-style-type: none"> <li>1. Compound dimension: 1.00×0.60 ;</li> <li>2. Unit: mm;</li> <li>3. General tolerance ±0.025 mm unless otherwise specified;</li> <li>4. The layout is just for reference.</li> </ol>
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#### Tape and Reel Orientation



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